



ZVP0545G

#### SOT223 P-CHANNEL ENHANCEMENT MODE VERTICAL DMOS FET

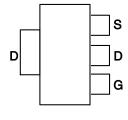
#### **Features and Benefits**

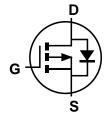
- 450 Volt V<sub>DS</sub>
- R<sub>DS(ON)</sub> = 150Ω
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

### **Mechanical Data**

- Case: SOT223
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish (§3)
- Weight: 0.112 grams (Approximate)







Pin Out - Top

**Equivalent Circuit** 

#### **Ordering Information** (Note 4)

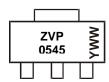
Part Number	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZVP0545GTA	ZVP0545	7	8	1,000

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

# **Marking Information**

SOT223



ZVP0545 = Product Type Marking Code YWW = Date Code Marking Y or  $\overline{Y}$  = Last Digit of Year (ex: 5= 2015) WW or  $\overline{W}W$  = Week Code (01 to 53)



# **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Drain-Source Voltage	$V_{DSS}$	-450	V
Gate-Source Voltage	$V_{GSS}$	±20	V
Continuous Drain Current	I <sub>D</sub>	-75	mA
Pulsed Drain Current	$I_{DM}$	-150	mA

### Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation	$P_{D}$	2	W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

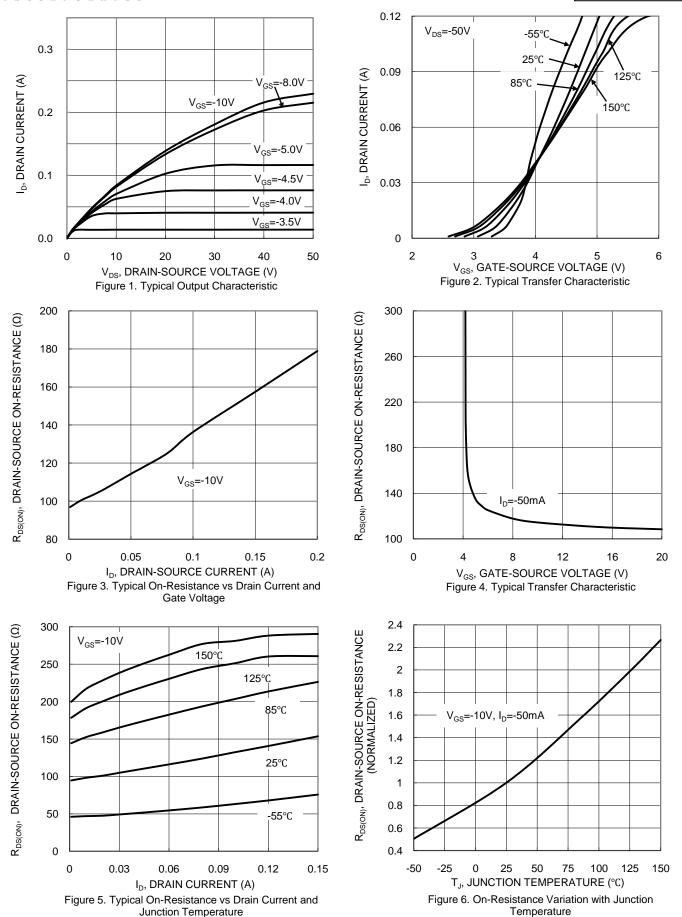
### Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-450	-	-	V	$V_{GS} = 0V$ , $I_D = 1mA$	
Zero Gate Voltage Drain Current (T <sub>J</sub> = +25°C)	I <sub>DSS</sub>	-	-	-20 -2	μA mA	$V_{DS} = -450V, V_{GS} = 0V$ $V_{DS} = -360V, V_{GS} = 0V,$ $T_A = +125^{\circ}C \text{ (Note 6)}$	
Gate-Source Leakage	I <sub>GSS</sub>	-	-	20	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
On-State Drain Current (Note 5)	I <sub>D(ON)</sub>	-100	-	-	mA	$V_{GS} = -10V, V_{DS} = -25V$	
ON CHARACTERISTICS							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	-1.5	-	-4.5	V	$V_{DS} = V_{GS}$ , $I_D = -1mA$	
Static Drain-Source On-Resistance (Note 5)	R <sub>DS(ON)</sub>	-	-	150	Ω	$V_{GS} = -10V, I_{D} = -50mA$	
Forward Transconductance (Note 5)(Note 6)	9fs	40	-	-	mS	$V_{DS} = -25V, I_{D} = -50mA$	
DYNAMIC CHARACTERISTICS (Note 6)							
Input Capacitance	C <sub>iss</sub>	-	-	120	pF		
Output Capacitance	Coss	-	-	20	pF	$V_{DS} = -25V$ , $V_{GS} = 0V$ , $f = 1.0MHz$	
Reverse Transfer Capacitance	C <sub>rss</sub>	-	-	5	pF	1	
Turn-On Delay Time (Note 7)	t <sub>D(ON)</sub>	-	-	10	ns		
Turn-On Rise Time (Note 7)	t <sub>R</sub>	-	-	15	ns	\\	
Turn-Off Delay Time (Note 7)	t <sub>D(OFF)</sub>	-	-	15	ns	$V_{DD} = -25V, I_D = -50mA$	
Turn-Off Fall Time (Note 7)	t <sub>F</sub>	-	-	20	ns		

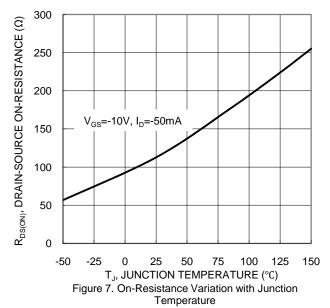
Notes:

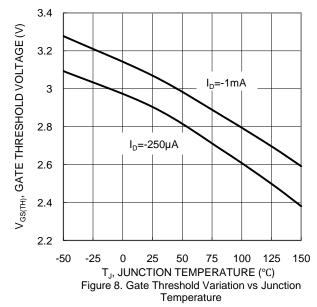
- 5. Measured under pulsed conditions. Width=300 $\mu$ s. Duty cycle ≤2%.
- 6. Sample test
- 7. Switching times measured with  $50\Omega$  source impedance and <5ns rise time on a pulse generator.

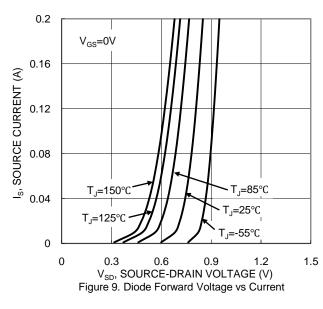


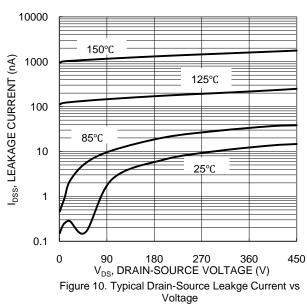


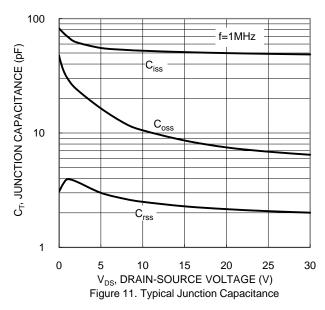


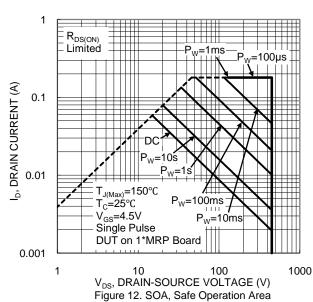














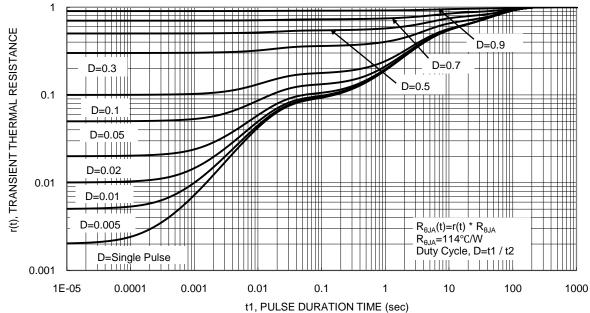
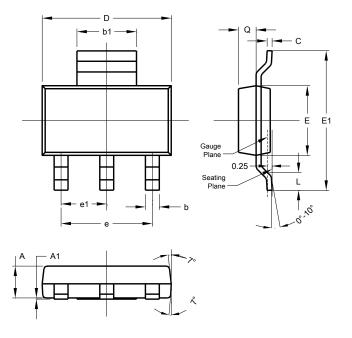


Figure 13. Transient Thermal Resistance



## **Package Outline Dimensions**

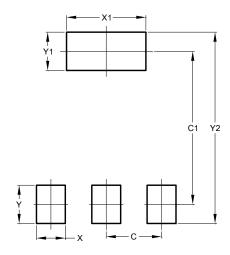
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



SOT223					
Dim	Min	Max	Тур		
Α	1.55	1.65	1.60		
A1	0.010	0.15	0.05		
b	0.60	0.80	0.70		
b1	2.90	3.10	3.00		
С	0.20	0.30	0.25		
D	6.45	6.55	6.50		
Е	3.45	3.55	3.50		
E1	6.90	7.10	7.00		
е	-	-	4.60		
e1	-	-	2.30		
L	0.85	1.05	0.95		
Q	0.84	0.94	0.89		
All Dimensions in mm					

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00



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